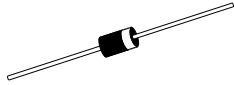


CRSH2 SERIES**SCHOTTKY BARRIER RECTIFIER
2.0 AMPS, 20 THRU 100 VOLTS****CASE DO-15**

CentralTM

Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CRSH2 Series types are Schottky Barrier Rectifiers mounted in an axial lead epoxy case using a metal to silicon junction to yield a low forward voltage drop.

MARKING: FULL PART NUMBER**MAXIMUM RATINGS:** ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

		CRSH2-							
	SYMBOL	<u>2</u>	<u>3</u>	<u>4</u>	<u>5</u>	<u>6</u>	<u>8</u>	<u>10</u>	UNITS
Peak Repetitive Reverse Voltage	V _{RRM}	20	30	40	50	60	80	100	V
DC Blocking Voltage	V _R	20	30	40	50	60	80	100	V
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	35	42	56	70	V
Average Forward Current (T _L =75°C)	I _O				2.0				A
Peak Forward Surge Current (8.3ms)	I _{FSM}				50				A
Operating and Storage Junction Temperature	T _J , T _{stg}				-65 to +125				°C
Thermal Resistance	Θ _{JA}				35				°C/W

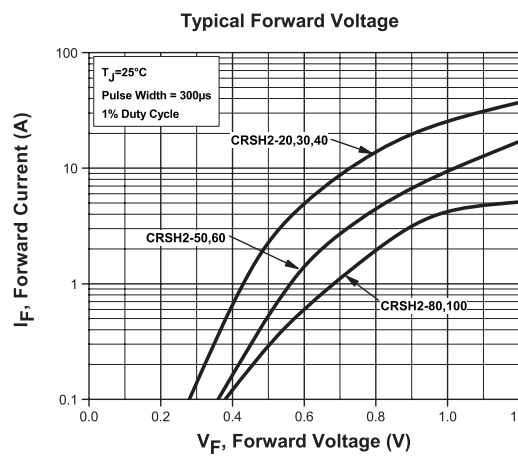
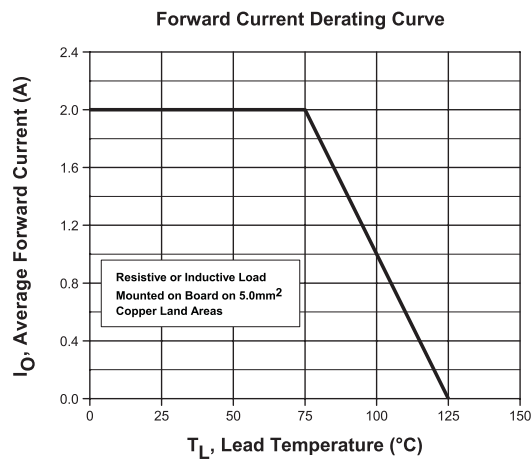
ELECTRICAL CHARACTERISTICS: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	TYP	MAX	UNITS
I_R	$V_R=\text{Rated } V_{RRM}$		0.5	mA
I_R	$V_R=\text{Rated } V_{RRM} (T_A=100^{\circ}\text{C})$		20	mA
V_F	$I_F=2.0\text{A (20V, 30V, 40V)}$		0.5	V
V_F	$I_F=2.0\text{A (50V, 60V)}$		0.7	V
V_F	$I_F=2.0\text{A (80V, 100V)}$		0.85	V
C_J	$V_R=4.0, f=1.0\text{MHz}$	170		pF

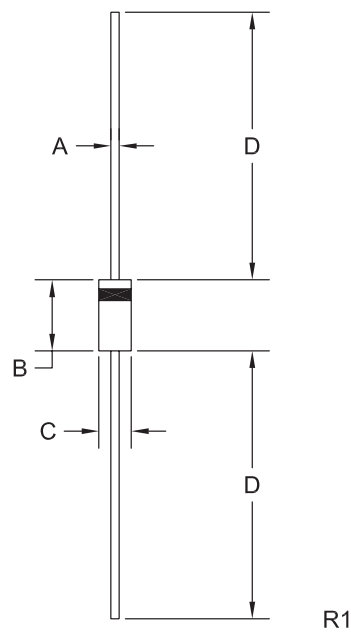
R2 (24-October 2008)

CRSH2 SERIES

SCHOTTKY BARRIER RECTIFIER
2.0 AMPS, 20 THRU 100 VOLTS



DO-15 CASE - MECHANICAL OUTLINE



DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.028	0.034	0.71	0.86
B	0.230	0.300	5.84	7.62
C	0.104	0.140	2.64	3.56
D	1.000	-	25.40	-

DO-15 (REV: R1)

MARKING: FULL PART NUMBER

R2 (24-October 2008)